

Thin-film Cu(In,Ga)Se₂ for flexible and lightweight photovoltaic applications

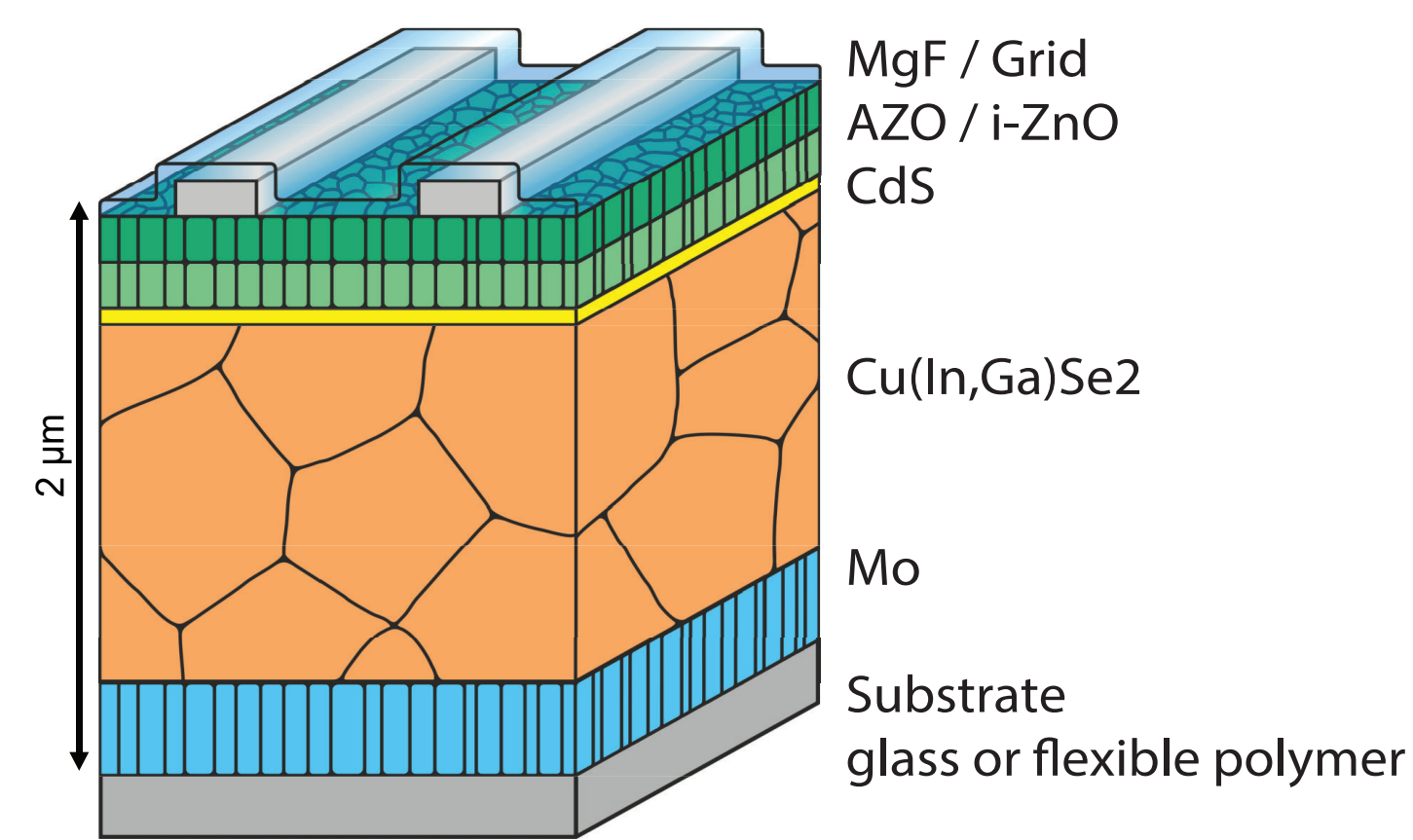
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Research Focus

High performance Cu(In,Ga)Se₂ (CIGS) solar cells on flexible substrates

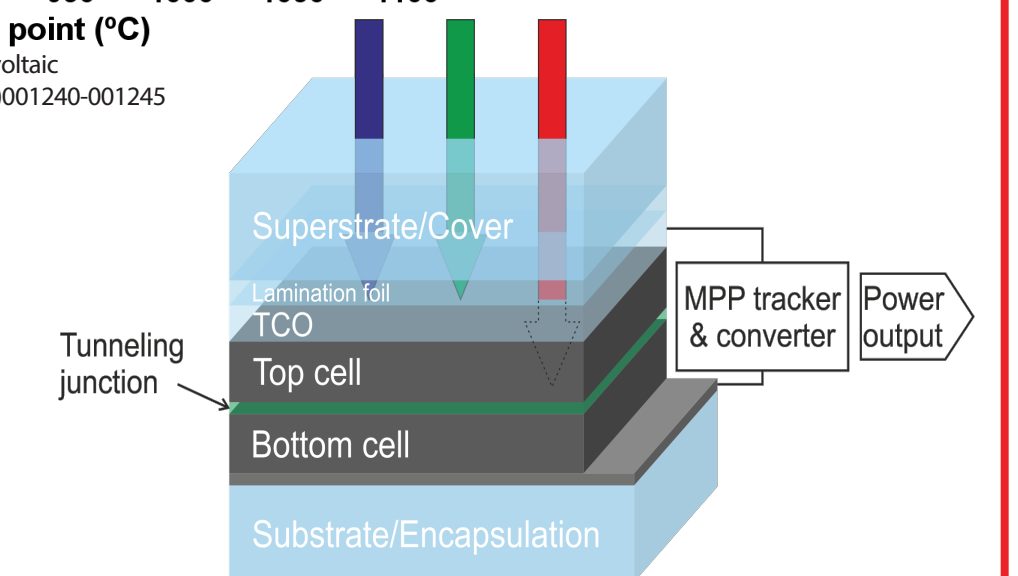
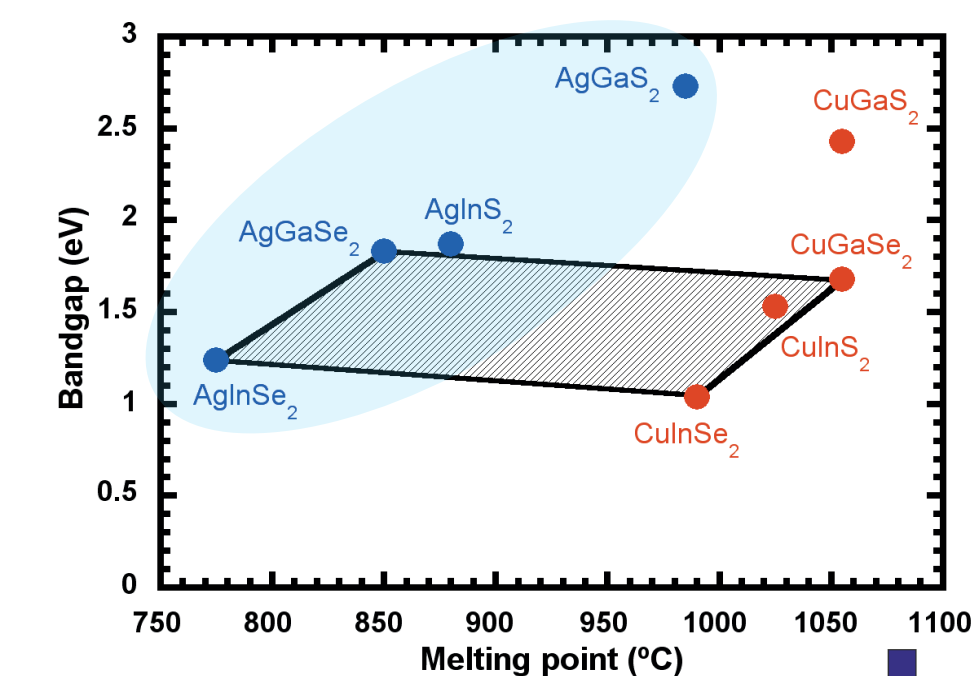


Advantages:

- Flexible, light weight (<2 kg/m² commercially available)
- Roll-to-roll processing
- Uniform appearance
- BIPV, mobility applications

Selected research activities

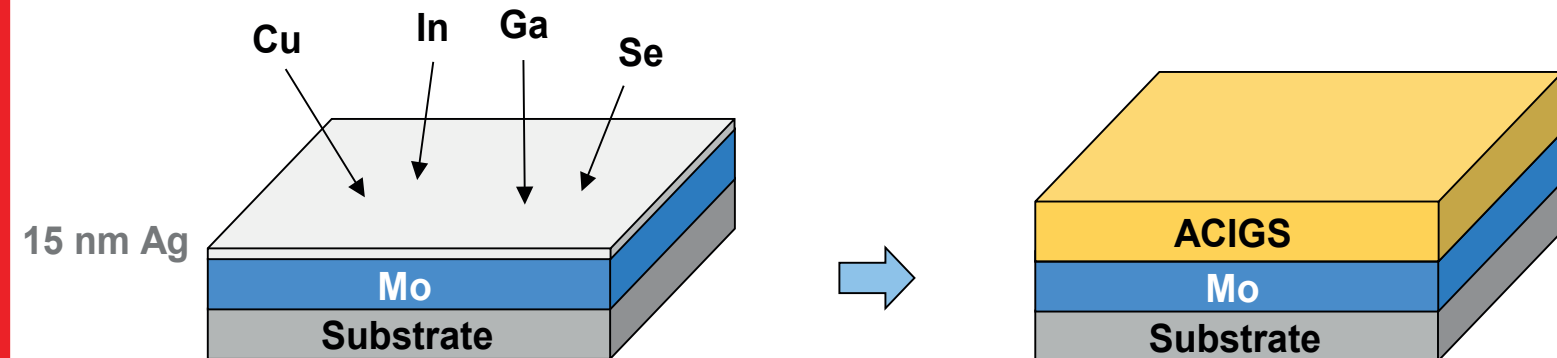
- High performance single junction devices
 - Process tailoring: composition, gradients, interfaces, doping
 - Flexible substrates
- Robust manufacturing processes
 - Relaxed processing requirements
Thermal budget, process control, etc.
 - Simplified manufacturing processes
Co-evaporation, doping, etc.
- Bottom cell for tandem devices
 - Low bandgap (1.0 eV for current matching)
 - Reduced surface roughness



Results

Lower deposition temperatures

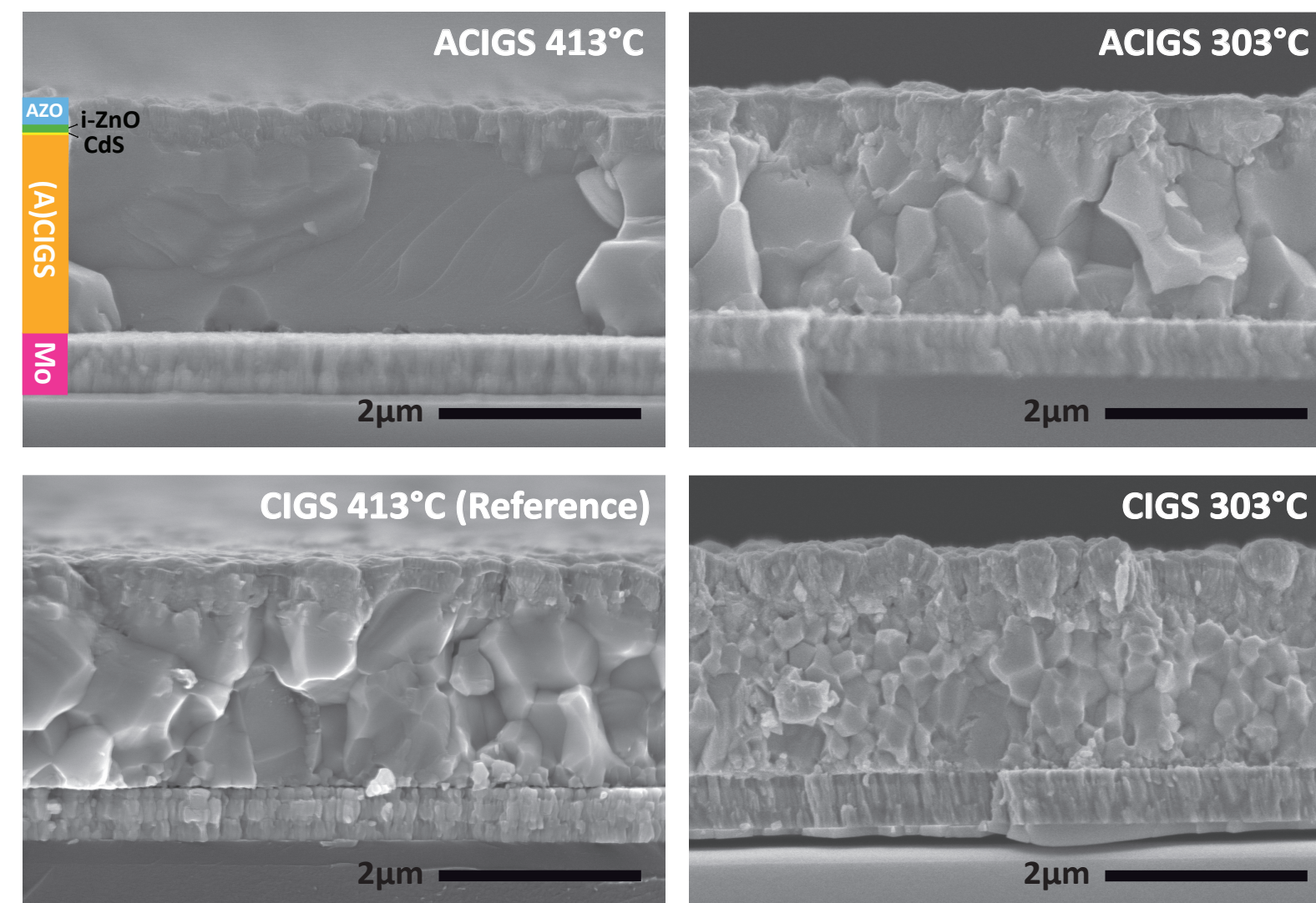
Modified deposition process:
Precursor layer before coevaporation



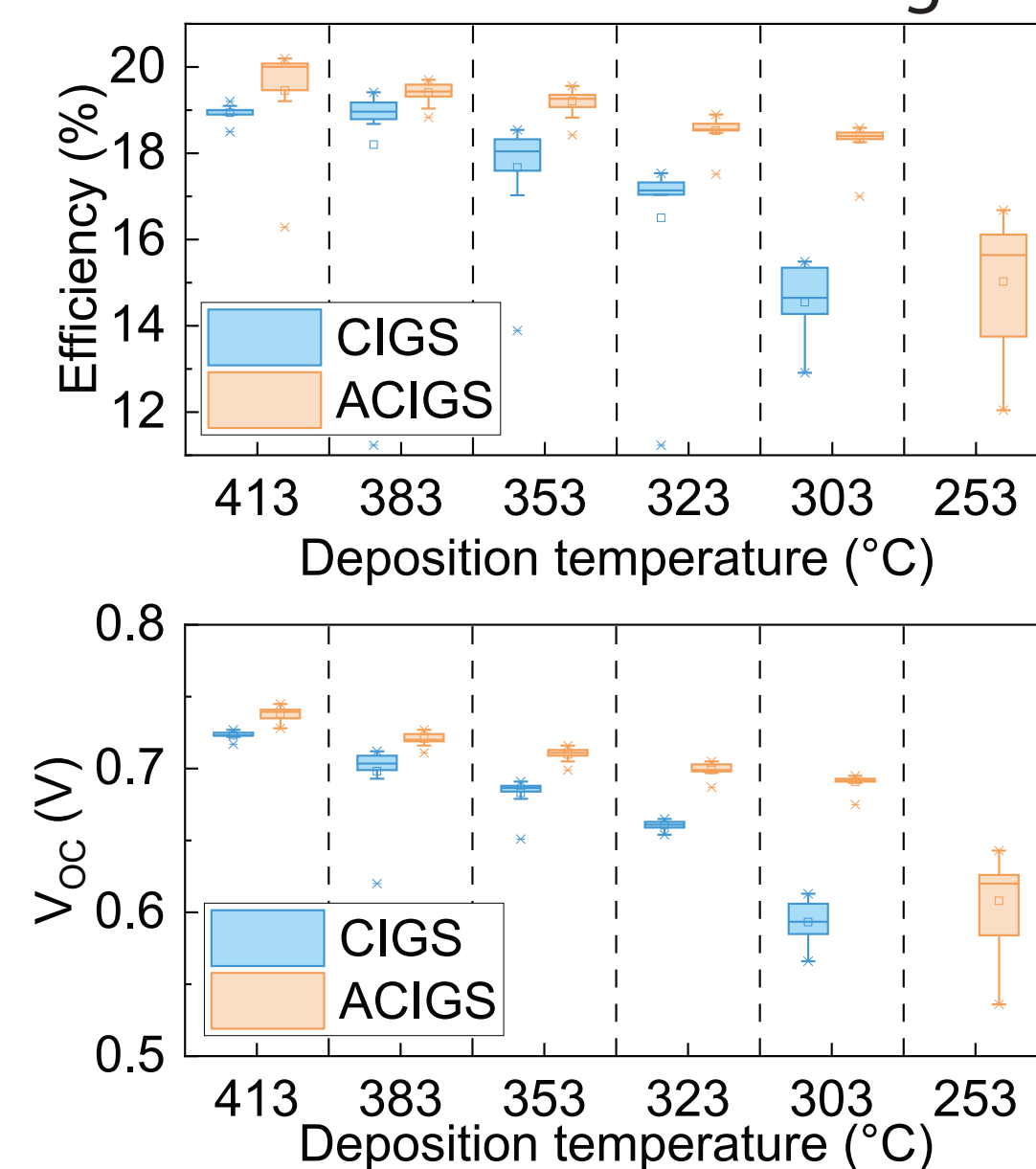
WHAT ARE WE INTERESTED IN ?

Robust processes, drastically
reduced deposition temperatures
High performing devices
Possible new devices architectures

Improved microstructure with small Ag amount



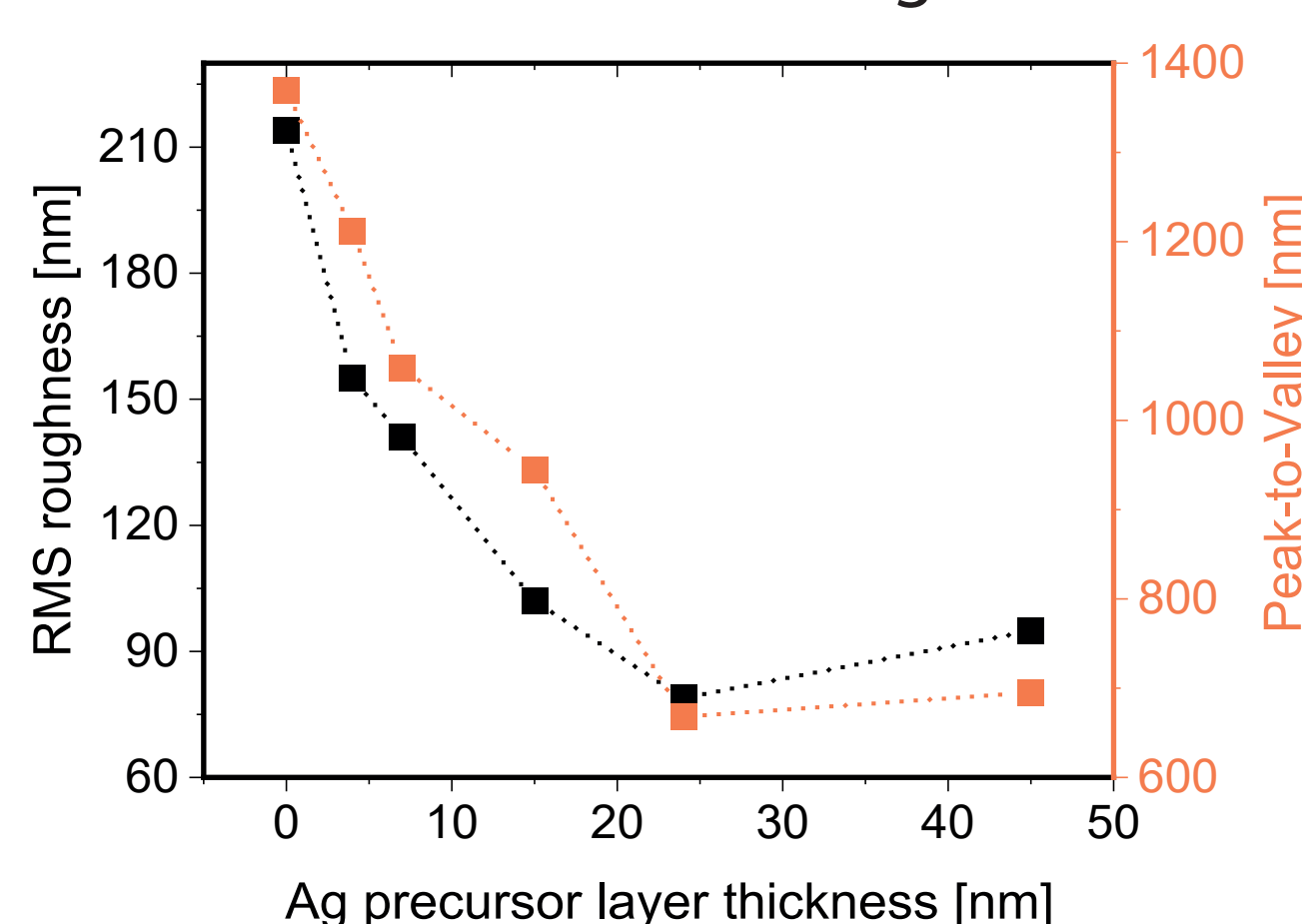
Wider processing window
Reduced thermal budget



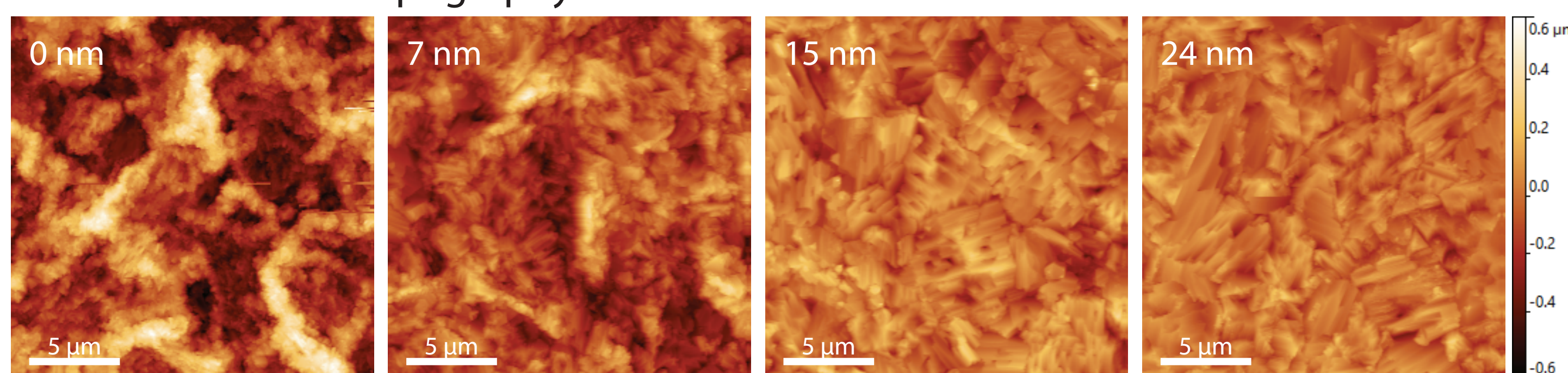
- Improved morphology, larger grain size, increased efficiency
- Reduced thermal budget, wider process tolerances (T, dopants)
- Minimal requirements on hardware change

Roughness reduction for tandem device applications

Reduced surface roughness

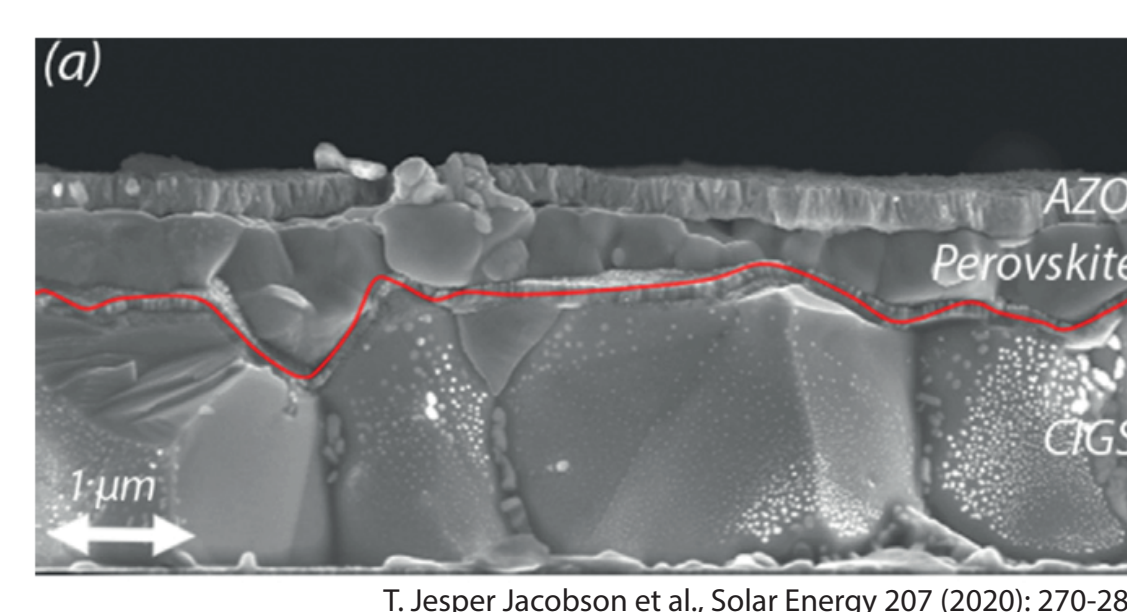


AFM surface topography



WHAT ARE WE INTERESTED IN ?

Reducing the surface roughness
for 2-terminal perovskite-CIS
tandem applications



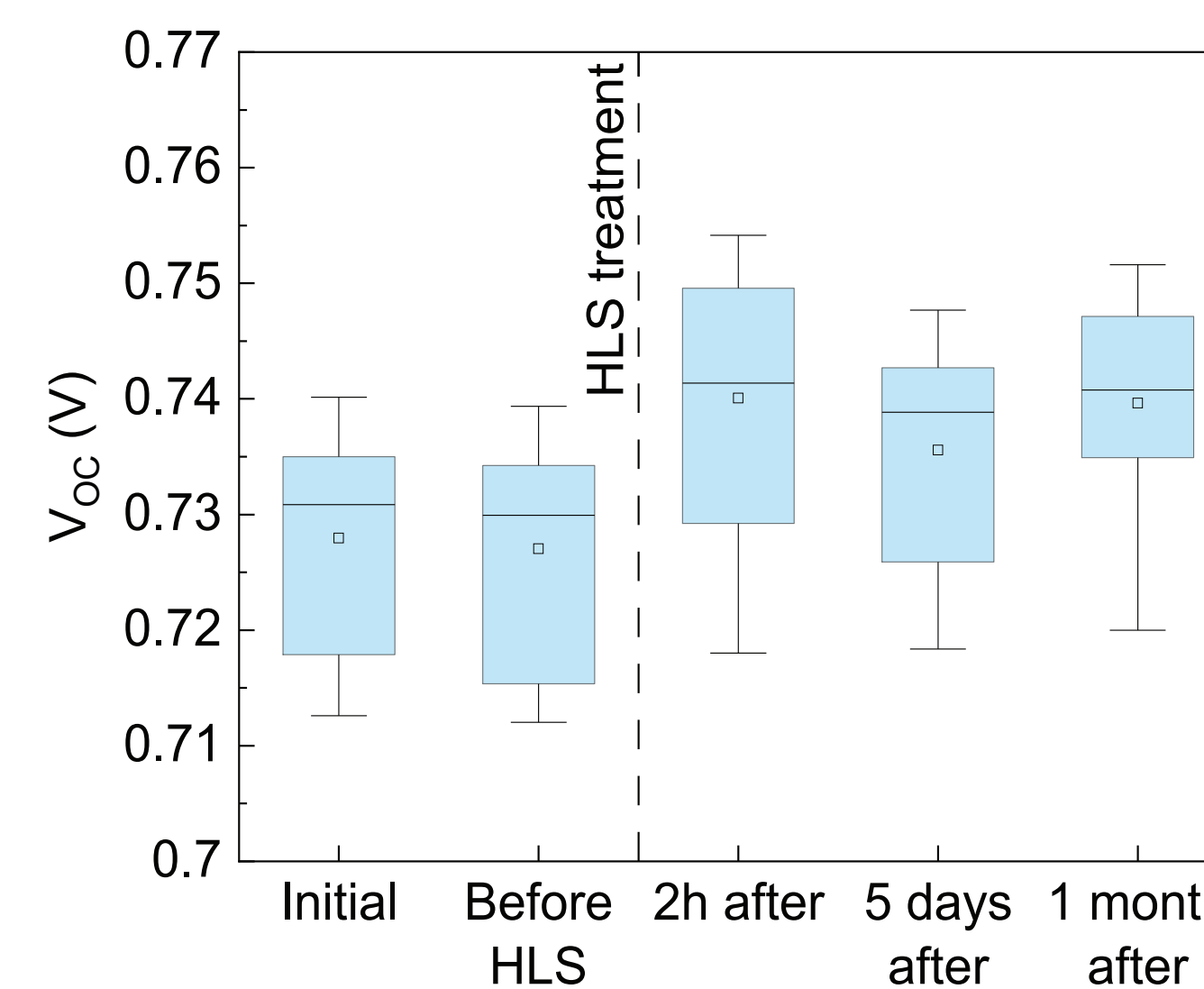
T. Jesper Jacobson et al., Solar Energy 207 (2020): 270-288

- Better suitability for two-terminal tandem devices
- Facilitated conformal coverage for thinner buffer layers

New efficiency record on flexible solar cells

Thermal treatment on finished devices
(heat light soaking)

- Improvements stable for months
- Evaluating industrialisation of findings



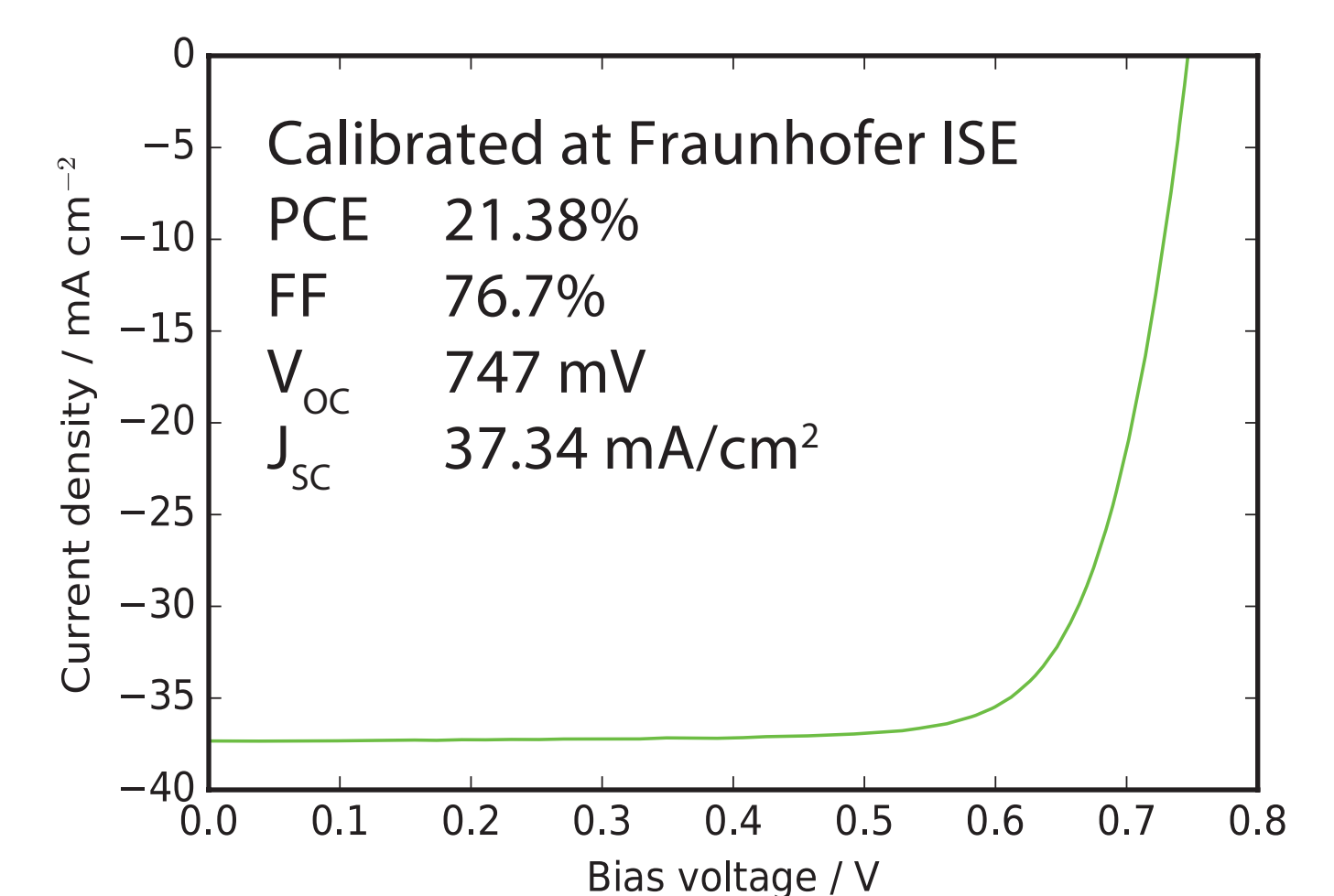
Increased device efficiency

- Increase in Voc (higher doping density)
- Stable or slight improvement in FF, Jsc
- Slight negative impact on non-rad. recomb.

WHAT ARE WE INTERESTED IN ?

High power conversion efficiency for
• Increased energy production
• More profitable PV installations
Demonstrate technology potential

New record flexible CIGS solar cells



- New record efficiency: 21.4% for CIGS on flexible substrate
- Thermal treatment for:
 - improved Voc
 - increased doping density

Summary

- New record efficiency: 21.4% on CIGS solar cell on flexible substrate
- Modified CIGS absorbers with small Ag amount
 - Improved morphology, larger grain size for higher efficiency
 - High efficiencies retained at 100°C lower temperature than state-of-the-art (413°C to 303°C)
 - Wider processing windows (temperature, alkali)
 - Precursor layer method: minimal hardware and process modification
- Reduced surface roughness, in view of monolithic tandem devices

Acknowledgement

This work received funding from the Swiss Federal Office of Energy (SFOE) under ImprocIS project (Contract no.: SI/501614-01), the Swiss State Secretary for Education, Research and Innovation (SERI) under contract number 17.00105 (EMPIR project HyMet) and the European Union's Horizon 2020 research and innovation programme under grant agreement No 850937.



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